

10/501080

DT04 Rec'd PCT/PTO 09 JUL 2004

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Hiroshi YOSHIDA**

Serial No.: **Not yet assigned**

(§371 of international application No. PCT/JP03/00139)

Filed: **July 9, 2004**

For: **METHOD FOR GETTERING TRANSITION METAL IMPURITIES
IN SILICON CRYSTAL**

Attorney Docket No.: **042440**

Customer Number: **38834**

PRELIMINARY AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

July 8, 2004

Sir:

Prior to calculation of the filing fee and examination of this application, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks begin on page 4 of this paper.